H1109 PCT

(12) INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

(19) World Intellectual Property Organization
International Bureau

(43) International Publication Date
12 August 2004 (12.08.2004)

PCT

(10) International Publication Number
WO 2004/068589 A1

(51) International Patent Classification[7]: H01L 29/786, 21/336, 29/423

(21) International Application Number: PCT/US2004/000963

(22) International Filing Date: 15 January 2004 (15.01.2004)

(25) Filing Language: English

(26) Publication Language: English

(30) Priority Data:
10/348,910 23 January 2003 (23.01.2003) US

(71) Applicant *(for all designated States except US)*: **ADVANCED MICRO DEVICES, INC.** [US/US]; One AMD Place, Mail Stop 68, P.O. Box 3453, Sunnyvale, CA 94088-3453 (US).

(72) Inventors; and

(75) Inventors/Applicants *(for US only)*: **KRIVOKAPIC, Zoran** [/US]; 2321 De Varona Place, Santa Clara, CA 95050 (US). **AN, Judy, Xilin** [/US]; 905 Raintree Court, San Jose, CA 95129 (US). **DAKSHINA-MURTHY, Srikanteswara** [/US]; 10926 Jollyville Road, # 1423, Austin, TX 78759 (US). **WANG, Haihong** [/US]; 34170 Donahue Terrace, Fremont, CA 94555 (US). **YU, Bin** [/US]; 1373 Poppy Way, Cupertino, CA 95014 (US).

(74) Agent: **COLLOPY, Daniel, R.**; One AMD Place, Mail Stop 68, P.O.Box 3453, Sunnyvale, CA 94088-3453 (US).

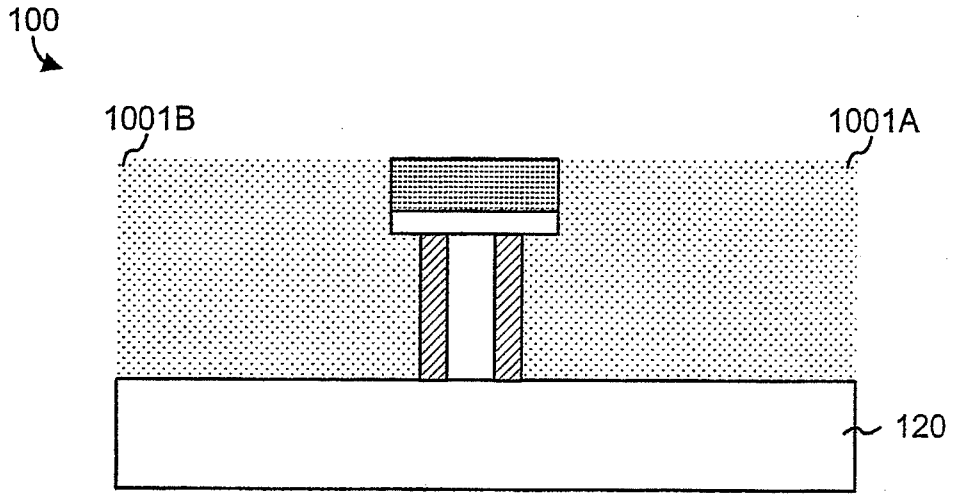
(81) Designated States *(unless otherwise indicated, for every kind of national protection available)*: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW.

(84) Designated States *(unless otherwise indicated, for every kind of regional protection available)*: ARIPO (BW, GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW), Eurasian (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IT, LU, MC, NL, PT, RO, SE, SI, SK, TR), OAPI (BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG).

Published:
— *with international search report*
— *before the expiration of the time limit for amending the claims and to be republished in the event of receipt of amendments*

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

(54) Title: NARROW FIN FINFET



(57) Abstract: A narrow channel FinFET is described herein with a channel width of less than 6 nm. The FinFET may include a fin (140) in which the channel area is trimmed using a NH_4OH etch or a reactive ion etch (RIE).

WO 2004/068589 A1